NSN 5962-01-358-9090

Memory Microcircuit - Page 1 of 1



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End Application:

Ac/rmpe react basic

Features Provided:

Electrostatic sensitive

Criticality Code Justification:

Cbbl

Memory Device Type:

Prom

Special Features:

Esd; hci. Item altered from p/n 15-1326286-1

Nuclear Hardness Critical Feature:

Hardened

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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